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Renesas Technology Corp.
Customer Support Dept.
April 1, 2003

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HD74LVCR2245A

Octal Bidirectional Transceivers with 3–state Outputs



ADE-205-235B (Z)

3rd. Edition
January 2001

Description

The HD74LVCR2245A has eight buffers with three state outputs in a 20 pin package. When (T / \bar{R}) is high, data flows from the A inputs to the B outputs, and when (T / \bar{R}) is low, data flows from the B inputs to the A outputs. A and B bus are separated by making enable input (\overline{OE}) high level.

All outputs, which are designed to sink up to 12 mA, include equivalent 26 Ω resistors to reduce overshoot and undreshoot.

Low voltage and high speed operation is suitable at battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 1.65$ to 5.5 V
- All inputs $V_{IH} (\text{Max}) = 5.5$ V (@ $V_{CC} = 0$ to 5.5 V)
- All inputs / outputs $V_{I/O} (\text{Max}) = 5.5$ V (@ $V_{CC} = 0$ V or output off state)
- Typical V_{OL} ground bounce < 0.8 V (@ $V_{CC} = 3.3$ V, $T_a = 25^\circ\text{C}$)
- Typical V_{OH} undershoot > 2.0 V (@ $V_{CC} = 3.3$ V, $T_a = 25^\circ\text{C}$)
- High output current ± 12 mA (@ $V_{CC} = 3.0$ to 5.5 V)
- All outputs have equivalent 26 Ω series resistors, so no external resistors are required

Function Table

Inputs		Operation
\overline{OE}	T / \overline{R}	
L	L	B data to A bus
L	H	A data to B bus
H	X	Z

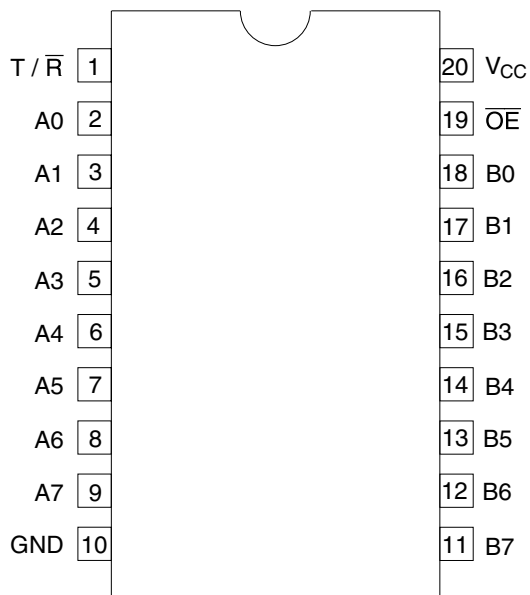
H : High level

L : Low level

X : Immaterial

Z : High impedance

Pin Arrangement



(Top view)

Absolute Maximum Ratings

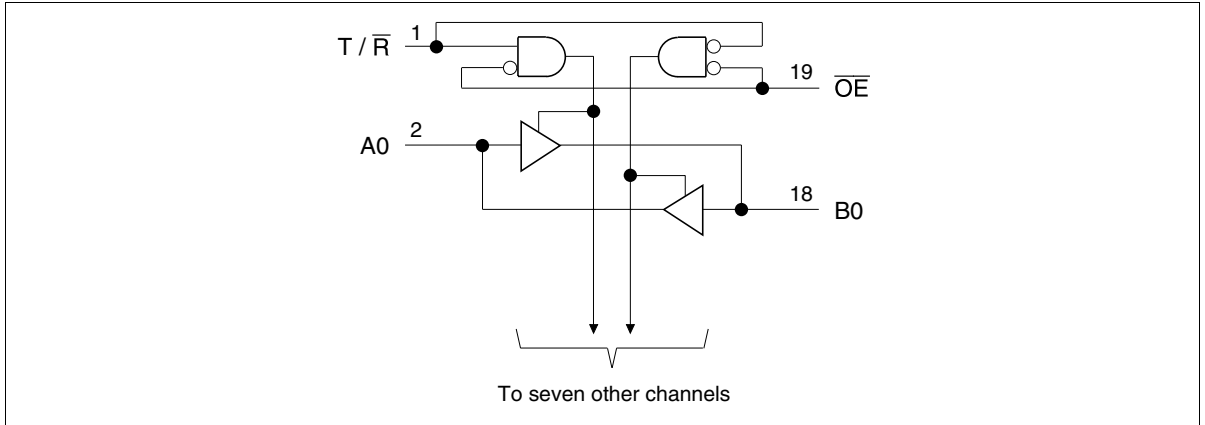
Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	-0.5 to 7.0	V	
Input voltage	V_I	-0.5 to 7.0	V	
Output voltage	V_O	-0.5 to 7.0 -0.5 to $V_{CC}+0.5$	V	Output "Z" or V_{CC} : OFF Output "H" or "L"
Input diode current	I_{IK}	-50	mA	$V_I < 0$
Output diode current	I_{OK}	-50	mA	$V_O < 0$
Output current	I_O	± 50	mA	
V_{CC} , GND current	I_{CC} or I_{GND}	± 100	mA	
Storage temperature	T_{stg}	-65 to 150	°C	

Note: The absolute maximum ratings are values which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	1.65 to 5.5 1.5 to 5.5	V	At operation Data retention only
Input voltage	V_I	0 to 5.5	V	
Output voltage	V_O	0 to 5.5 0 to V_{CC}	V	Output "Z" or V_{CC} : OFF Output "H" or "L"
Output current	I_{OH}	-2 -4 -8 -12	mA	$V_{CC} = 1.65$ V $V_{CC} = 2.3$ V $V_{CC} = 2.7$ V $V_{CC} = 3.0$ to 5.5 V
	I_{OL}	2 4 8 12		$V_{CC} = 1.65$ V $V_{CC} = 2.3$ V $V_{CC} = 2.7$ V $V_{CC} = 3.0$ to 5.5 V
Input rise / fall time	t_r, t_f	0 to 6	ns / V	
Operating temperature	T_a	-40 to +85	°C	

Logic Diagram



Electrical Characteristics (Ta = -40 to 85°C)

Item	Symbol	V _{cc} (V)	Min	Typ	Max	Unit	Test Conditions
Input voltage	V _{IH}	1.65 to 1.95	V _{cc} ×0.65	—	—	V	
		2.3 to 2.7	1.7	—	—		
		2.7 to 3.6	2.0	—	—		
		4.5 to 5.5	V _{cc} ×0.7	—	—		
	V _{IL}	1.65 to 1.95	—	—	V _{cc} ×0.35		
		2.3 to 2.7	—	—	0.7		
		2.7 to 3.6	—	—	0.8		
		4.5 to 5.5	—	—	V _{cc} ×0.3		
Output voltage	V _{OH}	1.65 to 5.5	V _{cc} -0.2	—	—	V	I _{OH} = -100 μA
		1.65	1.2	—	—		I _{OH} = -2 mA
		2.3	1.7	—	—		I _{OH} = -4 mA
		2.7	2.2	—	—		
		3.0	2.4	—	—		I _{OH} = -6 mA
		2.7	2.0	—	—		I _{OH} = -8 mA
		3.0	2.0	—	—		I _{OH} = -12 mA
	4.5	3.6	—	—			
	V _{OL}	1.65 to 5.5	—	—	0.2		I _{OL} = 100 μA
		1.65	—	—	0.45		I _{OL} = 2 mA
		2.3	—	—	0.7		I _{OL} = 4 mA
		2.7	—	—	0.4		
		3.0	—	—	0.55		I _{OL} = 6 mA
		2.7	—	—	0.6		I _{OL} = 8 mA
3.0		—	—	0.8	I _{OL} = 12 mA		
4.5	—	—	0.8				
Input current	I _{IN}	0 to 5.5	—	—	±5	μA	V _{IN} = 0 to 5.5 V
Off state output current	I _{OZ}	1.65 to 5.5	—	—	±5	μA	V _{OUT} = 0 to 5.5 V
Output leak current	I _{OFF}	0	—	—	±5	μA	V _{IN} or V _O = 5.5 V
Quiescent supply current	I _{CC}	1.65 to 3.6	—	—	10	μA	V _{IN} = 3.6 to 5.5 V ¹⁾ , I _O = 0
		1.65 to 5.5	—	—	10		V _{IN} = V _{CC} or GND
	ΔI _{CC}	2.7 to 3.6	—	—	500		V _{IN} = one input at (V _{CC} -0.6)V, other inputs at V _{CC} or GND
Input capacitance	C _{IN}	3.3	—	3.4	—	pF	V _{IN} = V _{CC} or GND
Input output capacitance	C _{I/O}	3.3	—	9.5	—	pF	V _{OUT} = V _{CC} or GND

Note: 1. This applies in the disabled state only.

Switching Characteristics (Ta = -40 to 85°C)

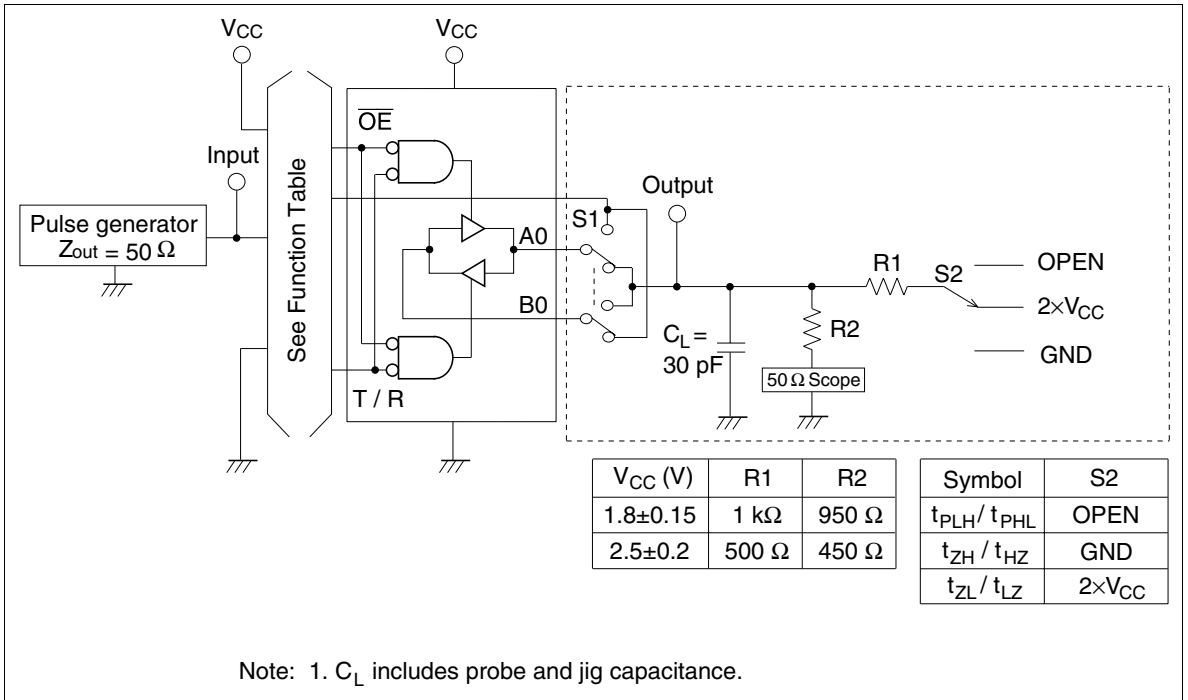
Item	Symbol	V _{CC} (V)	Min	Typ	Max	Unit	FROM (Input)	TO (Output)
Propagation delay time	t _{PLH}	1.8±0.15	—	—	15.0	ns	A or B	B or A
	t _{PHL}	2.5±0.2	—	—	9.0			
		2.7	—	—	7.3			
		3.3±0.3	1.5	—	6.3			
		5.0±0.5	—	—	4.8			
Output enable time	t _{ZH}	1.8±0.15	—	—	18.0	ns	\overline{OE}	A or B
	t _{ZL}	2.5±0.2	—	—	11.0			
		2.7	—	—	9.5			
		3.3±0.3	1.5	—	8.2			
		5.0±0.5	—	—	6.8			
Output disable time	t _{HZ}	1.8±0.15	—	—	16.0	ns	\overline{OE}	A or B
	t _{LZ}	2.5±0.2	—	—	10.0			
		2.7	—	—	8.5			
		3.3±0.3	1.7	—	7.8			
		5.0±0.5	—	—	6.6			
Between output pin skew ^{*1}	t _{OSLH}	1.8±0.15	—	—	2.0	ns		
	t _{OSHL}	2.5±0.2	—	—	2.0			
		2.7	—	—	1.5			
		3.3±0.3	—	—	1.0			
		5.0±0.5	—	—	1.0			

Note : 1. This parameter is characterized but not tested.

$$t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|$$

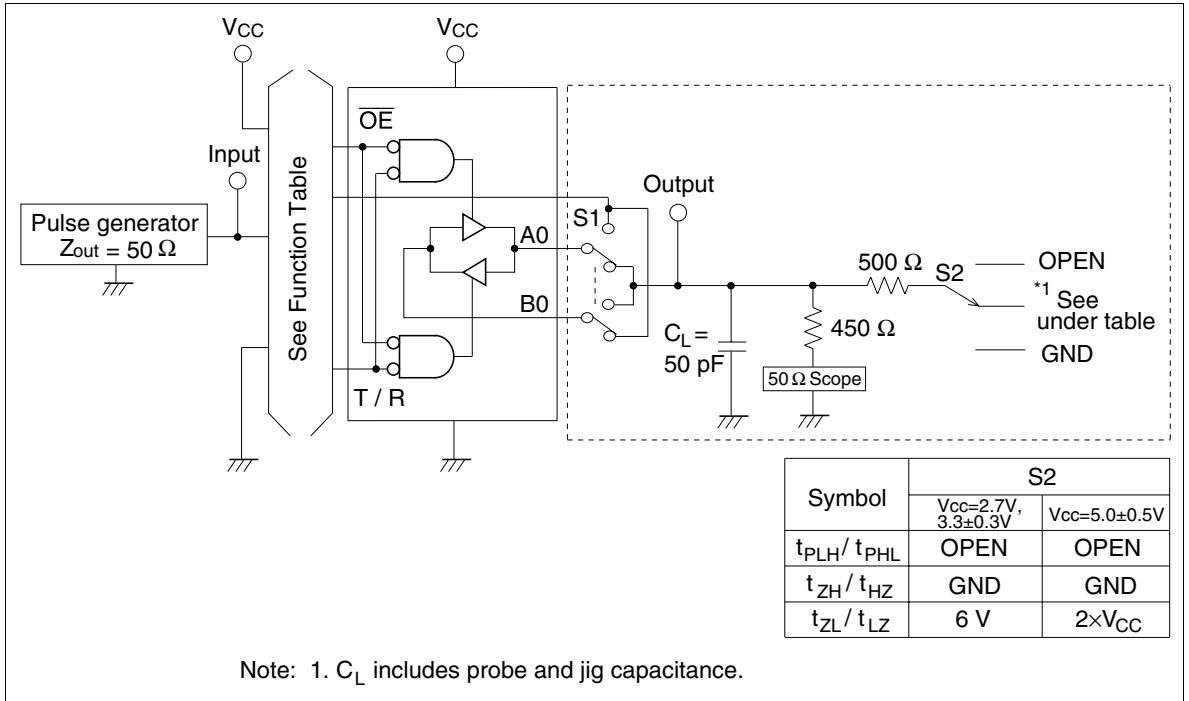
Test Circuit

($V_{CC} = 1.8 \pm 0.15 \text{ V}$, $V_{CC} = 2.5 \pm 0.2 \text{ V}$)



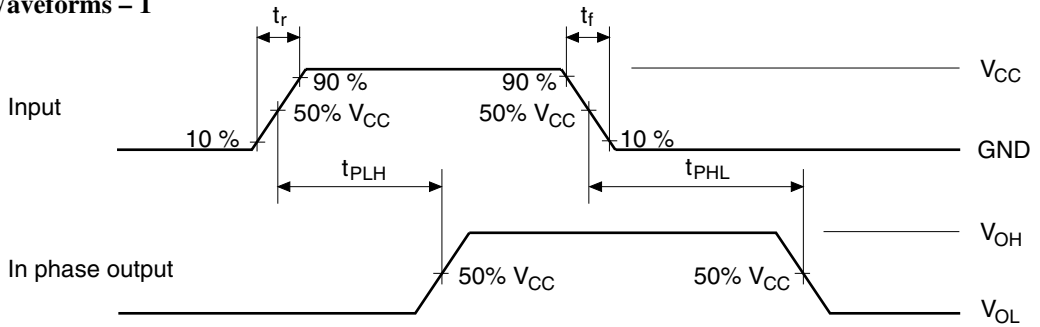
HD74LVCR2245A

($V_{CC} = 2.7\text{ V}$, $V_{CC} = 3.3 \pm 0.3\text{ V}$, $V_{CC} = 5.0 \pm 0.5\text{ V}$)

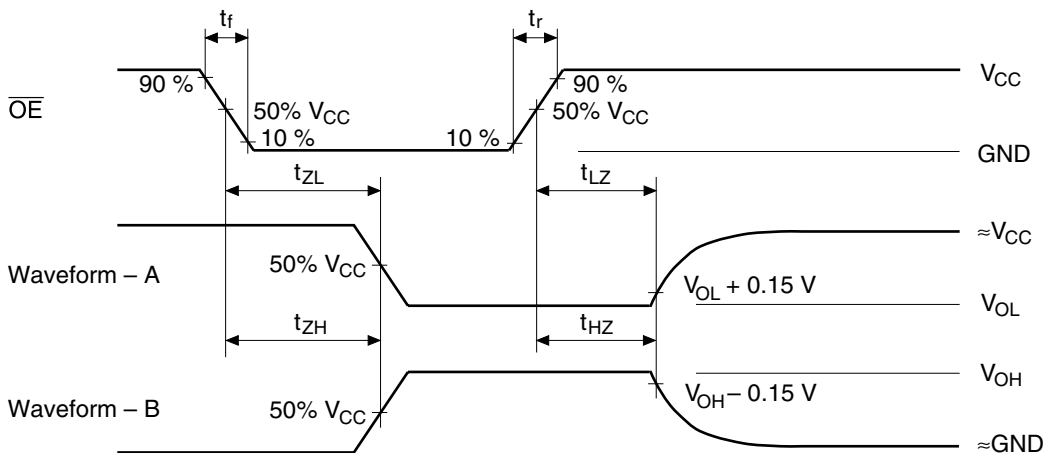


($V_{CC} = 1.8 \pm 0.15 \text{ V}$, $V_{CC} = 2.5 \pm 0.2 \text{ V}$)

• Waveforms – 1



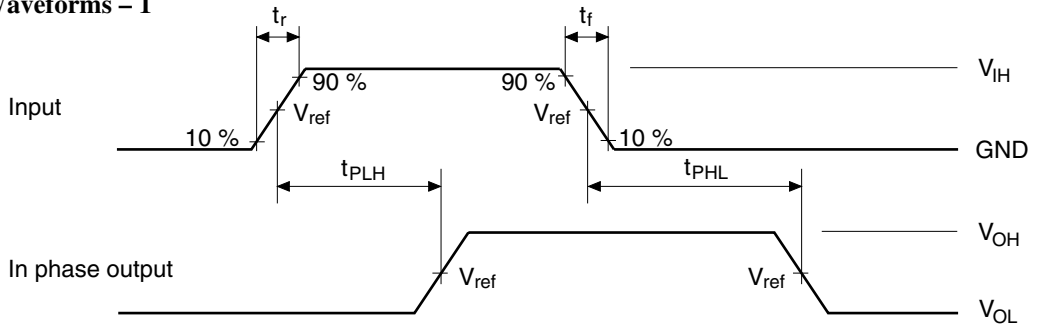
• Waveforms – 2



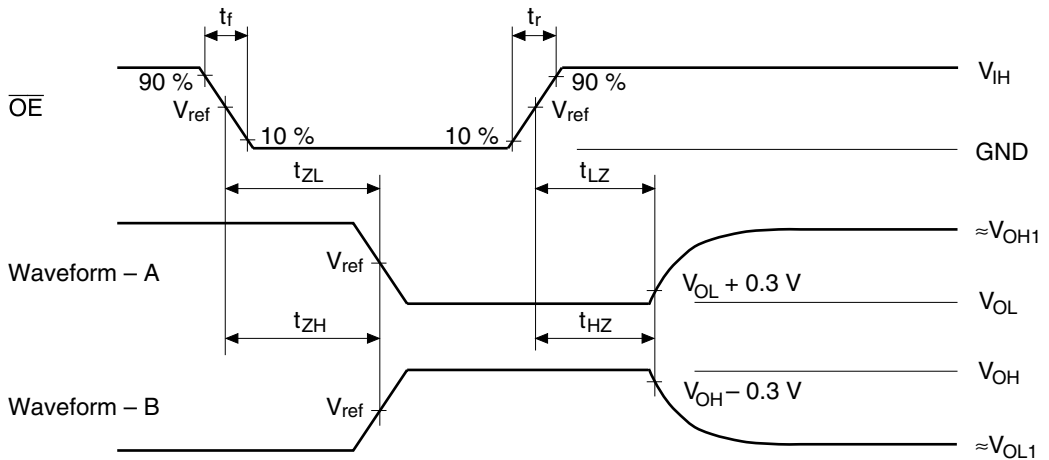
- Notes:
1. Input waveform : PRR = 10 MHz, duty cycle 50%, $t_r = 2.0 \text{ ns}$, $t_f = 2.0 \text{ ns}$
 2. Waveform – A shows input conditions such that the output is "L" level when enabled by the output control.
 3. Waveform – B shows input conditions such that the output is "H" level when enabled by the output control.

($V_{CC} = 2.7\text{ V}$, $V_{CC} = 3.3 \pm 0.3\text{ V}$, $V_{CC} = 5.0 \pm 0.5\text{ V}$)

• Waveforms – 1



• Waveforms – 2

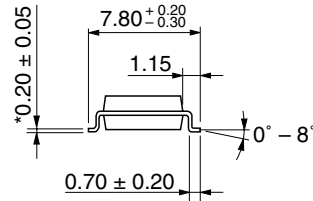
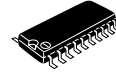
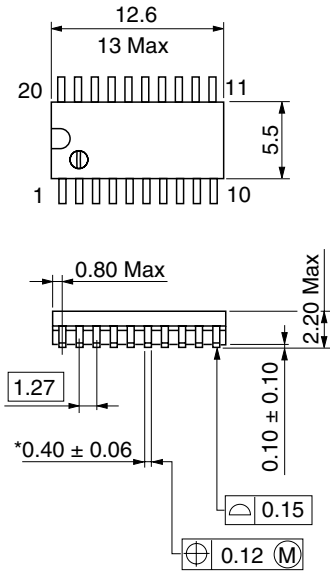


TEST	$V_{CC}=2.7\text{V}$ $3.3 \pm 0.3\text{V}$	$V_{CC}=5.0 \pm 0.5\text{V}$
V_{IH}	2.7 V	V_{CC}
V_{ref}	1.5 V	$50\%V_{CC}$
V_{OH1}	3 V	V_{CC}
V_{OL1}	GND	GND

- Notes:
1. Input waveform : PRR = 10 MHz, duty cycle 50%, $t_r = 2.5\text{ ns}$, $t_f = 2.5\text{ ns}$
 2. Waveform – A shows input conditions such that the output is "L" level when enabled by the output control.
 3. Waveform – B shows input conditions such that the output is "H" level when enabled by the output control.

Package Dimensions

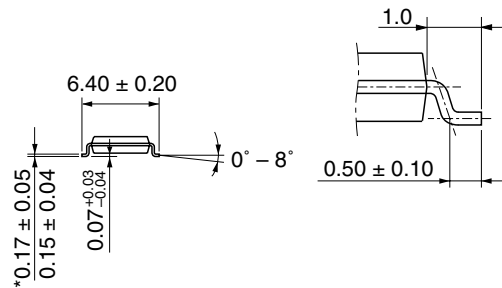
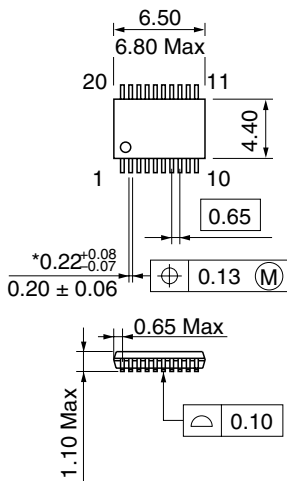
As of July, 2001
Unit: mm



*Pd plating

Hitachi Code	FP-20DAV
JEDEC	—
JEITA	Conforms
Mass (reference value)	0.31 g

As of July, 2001
Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	TTP-20DA
JEDEC	—
JEITA	—
Mass (reference value)	0.07 g

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Sales Offices**HITACHI****Hitachi, Ltd.**

Semiconductor & Integrated Circuits.
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL NorthAmerica : <http://semiconductor.hitachi.com/>
 Europe : <http://www.hitachi-eu.com/hel/ecg>
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For further information write to:

Hitachi Semiconductor
(America) Inc.
179 East Tasman Drive,
San Jose, CA 95134
Tel: <1>(408) 433-1990
Fax: <1>(408) 433-0223

Hitachi Europe GmbH
Electronic Components Group
Domacher StraÙe 3
D-85622 Feldkirchen, Munich
Germany
Tel: <49> (89) 9 9180-0
Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd.
Electronic Components Group.
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA, United Kingdom
Tel: <44> (1628) 585000
Fax: <44> (1628) 585160

Hitachi Asia Ltd.
Hitachi Tower
16 Collyer Quay #20-00,
Singapore 049318
Tel : <65>-538-6533/538-8577
Fax : <65>-538-6933/538-3877
URL : <http://www.hitachi.com.sg>

Hitachi Asia Ltd.
(Taipei Branch Office)
4/F, No. 167, Tun Hwa North Road,
Hung-Kuo Building,
Taipei (105), Taiwan
Tel : <886>-(2)-2718-3666
Fax : <886>-(2)-2718-8180
Telex : 23222 HAS-TP
URL : <http://www.hitachi.com.tw>

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower,
World Finance Centre,
Harbour City, Canton Road
Tsim Sha Tsui, Kowloon,
Hong Kong
Tel : <852>-(2)-735-9218
Fax : <852>-(2)-730-0281
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